

# Report Lab 1

Experimental Physics for AI 2

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## Chapter 1

# Measurement of the current-voltage characteristic of a resistor

## Chapter 2

# Measurement of the current-voltage characteristic of a diode

### 2.1 Goal

Now we want to measure the current-voltage characteristic of a diode, which should not be linear. Indeed, according to Shockley's law, it is exponential:

$$I = I_0 \left( e^{\frac{qV}{gkT}} - 1 \right)$$

where  $I_0$  is the reverse saturation current,  $q$  is the electron charge,  $k$  is the Boltzmann constant,  $T$  is the temperature, and  $g$  is the diode type-dependent constant. In this chapter we will try to verify this law.

Moreover for practical applications it's common practice to define the diode's *threshold voltage* as the voltage at which the diode starts conducting a "significant" current. We will try to measure this value as well.

### 2.2 Method

Using a similar setup as the one in part one, we recorded the measured values of current at different voltages. The setup is shown in figure 2.1, where the voltmeter is a handheld Fluke multimeter and the ammeter is a Agilent bench multimeter.

Later, in section 2.4, we will perform various fits to the data to verify the exponential relation and estimate the values of the parameters.

### 2.3 Data

The data we collected is shown in table and represented graphically in figure 2.2. The bench multimeter for the current measurements had an accuracy of  $\pm 0.05\% + 0.05\mu A$  in the  $500\mu A$  range; and the handheld multimeter had an accuracy of  $\pm 0.5\% + 0.002V$  in the  $2V$  range.

from the graph in figure 2.2 we can already see that after a certain voltage value (about 2.4) the graph follows accurately an exponential relationship, as expected. The previous values are very low in current and have a greater error. We will perform the analysis only on the part of the data which shows a clear exponential behavior, that is for voltages greater than 2.399 and currents greater than  $1.74\mu A$  (medium values).

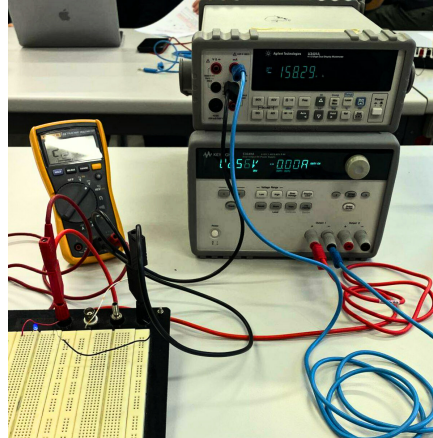
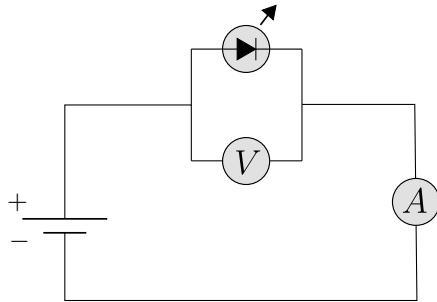


Figure 2.1: Setup of the diode experiment: on the left the diagram showing the circuit made, on the right a photo of the setup

## 2.4 Analysis

### 2.4.1 Shockley's law

We used the following approximation:

$$\ln(e^x - 1) \approx x \quad \text{for } x \gg 1 \quad (2.4.1)$$

so that we could linearize the relationship as

$$I = I_0 \left( e^{\frac{qV}{gkT}} - 1 \right) \approx I_0 e^{\frac{qV}{gkT}} \implies \log I \approx \frac{q}{gkT} V + \log I_0$$

Then we performed a linear regression on the data, with the errors on  $V$ . We decided to keep the error only in the independent variable since it was much greater than the one in the dependent variable. In R we ran the following commands:

```
1 diode.data <- read.csv("data.csv")
2 diode.selected <- diode.data[diode.data$Vdetapprox >= 2.399,]
3 logIerr <- diode.selected$IerrIdet/diode.selected$Idetapprox
4 diode.lm <- lm(log(Idetapprox) ~ Vdetapprox, data=diode.selected,
5                                     weights=1/logIerr^2)
6 summary(diode.lm)
```

obtaining the following result:

Coefficients:

	Estimate	Std. Error	t value	Pr(> t )
(Intercept)	-66.698	1.294	-51.55	<2e-16 ***
Vdetapprox	28.215	0.509	55.44	<2e-16 ***

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Signif. codes: 0 '\*\*\*' 0.001 '\*\*' 0.01 '\*' 0.05 '.' 0.1 ' ' 1

Residual standard error: 44.5 on 19 degrees of freedom

Multiple R-squared: 0.9939, Adjusted R-squared: 0.9935

F-statistic: 3073 on 1 and 19 DF, p-value: < 2.2e-16

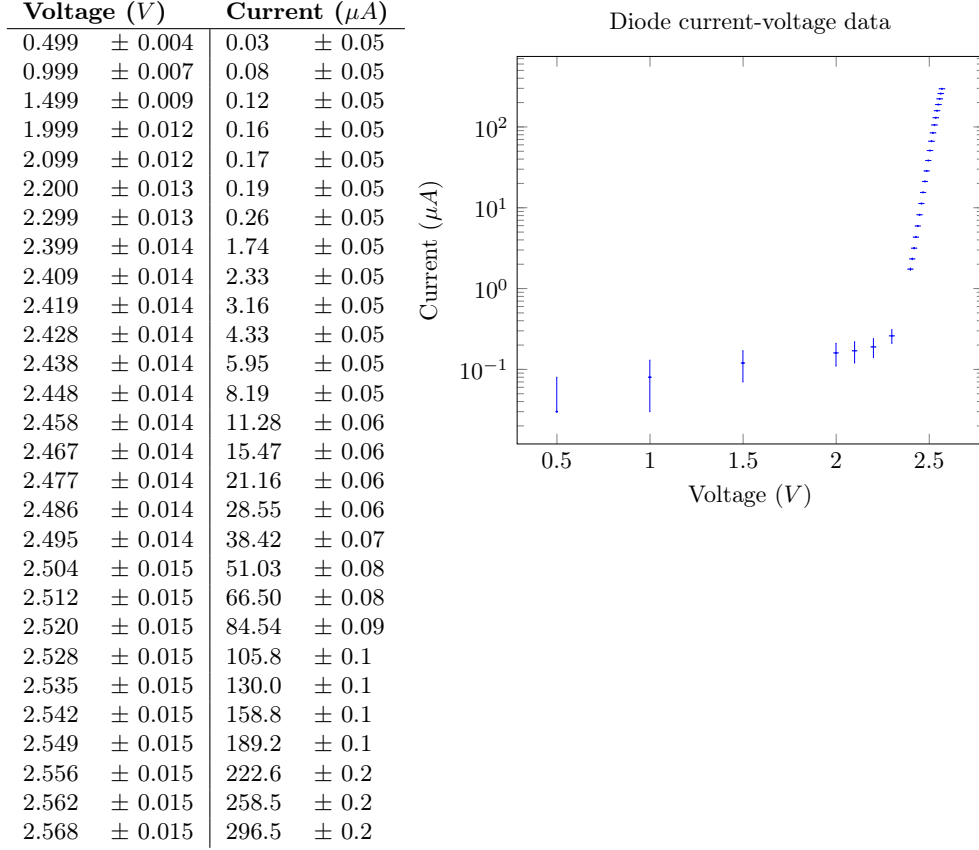


Figure 2.2: Data collected for the diode

So we can very confidently say that the relation between the current and the voltage is exponential. The formula is then:

$$\begin{aligned} \log I_0 &= -67 \pm 1 \implies I_0 = 10^{-29} \pm 10^{-29} \mu A \\ \frac{q}{gkT} &= 28.2 \pm 0.5 \implies g = \frac{38.6}{28.2} \mp \frac{0.5}{28.2} = 1.368 \pm 0.006 \\ I &\approx 1e - 29e^{\frac{q}{kT} \cdot \frac{1}{1.368} \cdot V} = 10^{-29} e^{28.2V} \mu A \end{aligned}$$

(We did not take the measurement for the temperature, so actually 38.6 here should not obviously be a constant, but as we don't have the measurement, we considered it as such, consequently the error on  $g$  is much smaller than the one it should be). In figure 2.3 we can see in a graph the accuracy of the fit. Now we can justify the approximation (2.4.1) as indeed for  $V \geq 2.4$  we clearly have that the exponent  $\frac{qV}{gkT} \geq 67.68 \gg 1$ , more precisely, if  $f, g : [67.68, \infty)$  are respectively the functions  $x \mapsto \ln(e^x - 1)$  and  $x \mapsto x$  then

$$\|f - g\|_\infty = |(f - g)(67.68)| \approx 4.05 \cdot 10^{-30}$$

**Chi-squared test** Finally, we performed a  $\chi^2$  test on the residuals of the fit to see if the errors were independent and normally distributed (assuming homoscedasticity), which is what we expect:

```
1 res <- exp(diode.lm$fitted.values) - diode.selected$Ideapprox
2 chisq <- sum(res^2 / var(res)) # assume homoscedasticity
```

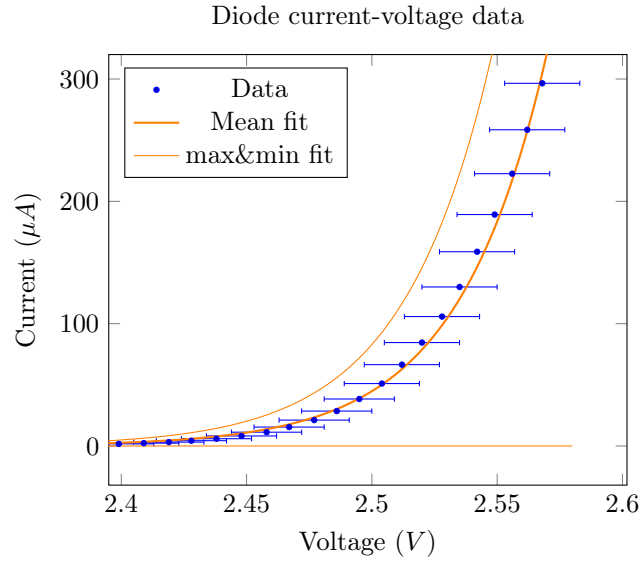


Figure 2.3: Exponential fit of the data

```
3 df <- length(diode.lm$residuals) - length(diode.lm$coefficients)
4 pval <- pchisq(chisq, df, lower.tail=FALSE)
5 pval
```

Which returns a p-value of  $0.29 > 0.05$ , so we can't reject the null hypothesis that the errors are independent and the fit is good.

## 2.4.2 Threshold voltage

As explained before, the *threshold voltage* is said to be the voltage at which a diode starts conducting a “significant” current. It's obtained by fitting the data as a linear relationship and then taking the x-intercept of the line. To decide how many points to take out of the selected ones, we will perform the  $\chi^2$  test to see if the residuals are independent normal random variables. The null hypothesis for each value of  $l$  (the number of points) is that the errors are independent and normally distributed, while the alternative hypothesis is that they are not. We will then take the biggest  $l$  such that we can't reject the null hypothesis. In R code this is:

```
1 l <- length(diode.selected$Vdetapprox)+1
2 pval <- 0
3 while (pval < 0.05) {
4   l = l - 1
5   diode.sel_thresh <- tail(diode.selected, l)
6   diode.lm_threshold <- lm(Idetapprox ~ Vdetapprox,
7                           data=diode.sel_thresh)
8   r = diode.lm_threshold$residuals
9   chisq <- sum(r^2 / abs(diode.lm_threshold$fitted.values))
10  pval <- pchisq(chisq, l - 2, lower.tail=FALSE)
11 }
12 summary(diode.lm_threshold)
```

obtaining that we need to keep the last 9 points. Finally we calculated the V-coordinate of the fitting line of those 9 points. Since we know from the linear model that the line has equation  $i = mv + q$ , with  $m$  and  $q$  parameters saved in the variable

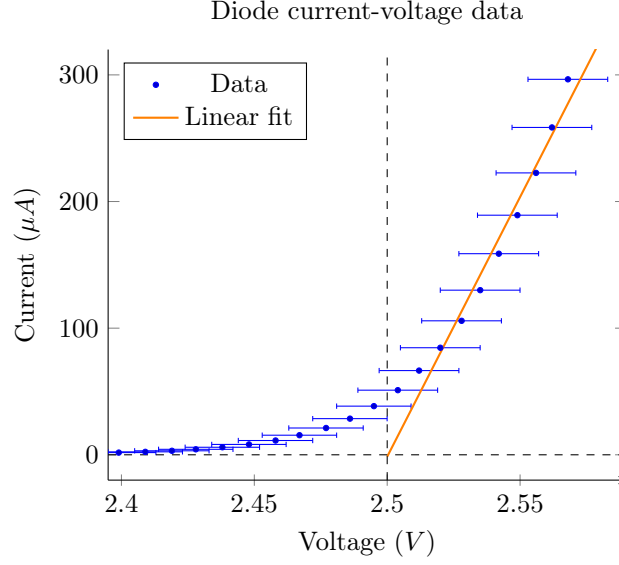


Figure 2.4: Threshold voltage

`diode.lm_threshold$coefficients`, and we obtain

$$q = -10.3 \pm 0.6 \text{ mA} \quad m = 4.1 \pm 0.2 \text{ mA/V}$$

$$\Rightarrow V_{\text{threshold}} = \frac{10.3}{4.1} \pm \sqrt{\left(\frac{0.6}{-10.3}\right)^2 + \left(\frac{0.2}{4.1}\right)^2} = 2.50 \pm 0.8 \text{ V}$$

## 2.5 Conclusion

A clear improvement would be to measure the temperature of the room in order to have a more precise value of the constant  $g$ . Moreover, If we had more datapoints, we could have performed a more accurate fit and have smaller errors.

That said, we have successfully verified Shockley's law for a diode and estimated the value of the parameters. We also measured the threshold voltage of the diode. The results are consistent with the theory: for silicon diodes the ideality factor  $g$  should be between 1 and 2, and the threshold voltage makes sense that is around 2.5V, since our diode was a blue LED, so if we see the threshold voltage as the voltage at which the LED starts emitting light, the first photon has energy  $E = h\nu$  with  $\nu = c/\lambda$ ,  $c$  the speed of light and  $h$  Planck's constant. If we add  $E = qV_{\text{threshold}}$  and solve for the wavelength  $\lambda$  we get

$$\lambda = \frac{hc}{qV_{\text{threshold}}} \approx 496 \text{ nm}$$

which is in the range of blue light.